

FEATURES

- Designed to Be Used in Voltage-Limiting Applications
- 3.5-Ω On-State Connection Between Ports A and B
- Flow-Through Pinout for Ease of Printed Circuit Board Trace Routing
- Direct Interface With GTL+ Levels
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DESCRIPTION/ORDERING INFORMATION

The SN74TVC3306 provides three parallel NMOS pass transistors with a common unbuffered gate. The low on-state resistance of the switch allows connections to be made with minimal propagation delay.

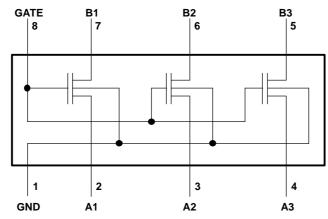
The device can be used as a dual switch, with the gates cascaded together to a reference transistor. The low-voltage side of each pass transistor is limited to a voltage set by the reference transistor. This is done to protect components with inputs that are sensitive to high-state voltage-level overshoots.

ORDERING INFORMATION

T _A PACKAGE ⁽¹⁾			ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	SSOP – DCT	Tape and reel	SN74TVC3306DCTR	FA6
-40 C 10 65 C	VSSOP - DCU	Tape and reel	SN74TVC3306DCUR	FA6

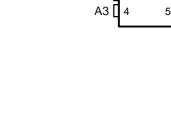
(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

LOGIC DIAGRAM (POSITIVE LOGIC)



NOTE A: The SN74TVC3306 has bidirectional capability across many voltage levels. The voltage levels documented in this data sheet are examples.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



GND [

A1 12

A2 🛙 3

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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SN74TVC3306 DUAL VOLTAGE CLAMP

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8 GATE

B3

7 🛛 B1

6 **1** B2

DCT OR DCU PACKAGE

(TOP VIEW)

SN74TVC3306 DUAL VOLTAGE CLAMP

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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

				MIN	MAX	UNIT
VI	Input voltage range ⁽²⁾			-0.5	7	V
V _{I/O}	Input/output voltage range ⁽²⁾				7	V
	Continuous channel current				128	mA
I _{IK}	Input clamp current	V ₁ < 0			-50	mA
0	Dealized the median edge of (3)	DCT package			220	0 0 000
θ_{JA}	Package thermal impedance ⁽³⁾	DCU package			227	°C/W
T _{stg}	Storage temperature range			-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(3) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions

		-	MIN	MAX	UNIT
V _{I/O}	Input/output voltage	3, 35, 14	0	5	V
V _{GATE}	GATE voltage	1 St. 38	0	5	V
I _{PASS}	Pass transistor current	23		64	mA
T _A	Operating free-air temperature		-40	85	°C

Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIO	NS	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IK}	l _l = -18 mA,	V _{GATE} = 0				-1.2	V
I _{IH}	$V_{I} = 5 V,$	V _{GATE} = 0				5	μA
C _{i(GATE)}	$V_1 = 3 V \text{ or } 0$				11		pF
C _{io(off)}	$V_0 = 3 \vee \text{ or } 0,$	$V_{GATE} = 0$			4	6	pF
C _{io(on)}	$V_{O} = 3 V \text{ or } 0,$	$V_{GATE} = 3 V$			10.5	12.5	pF
	V ₁ = 0,		$V_{GATE} = 4.5 V$		3.5	5.5	
		$I_{0} = 64 \text{ mA}$	$V_{GATE} = 3 V$		4.7	7	
	v ₁ = 0,	10 – 04 MA	$V_{GATE} = 2.3 V$		6.3	9.5	
r _{on} ⁽²⁾			$V_{GATE} = 1.5 V$		25.5	32	Ω
	$V_1 = 2.4 V_2$	L = 15 mA	$V_{GATE} = 4.5 V$		4.8	7.5	
	$v_{\parallel} = 2.4 v_{\perp}$	l _O = 15 mA	$V_{GATE} = 3 V$		14.7	23	
	V _I = 1.7 V,	l _O = 15 mA	$V_{GATE} = 2.3 V$		11.3	16.5	

(1) All typical values are at $T_A = 25^{\circ}C$.

(2) Measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (A or B) terminals.

 ⁽²⁾ The input and input/output negative-voltage ratings may be exceeded if the input and input/output clamp-current ratings are observed.



AC Performance (Translating Down)

Switching Characteristics

over recommended operating free-air temperature range, V_{GATE} = 3.3 V, V_{IH} = 3.3 V, V_{IL} = 0, and V_{M} = 1.15 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	C _L = 5	0 pF	C _L = 3	60 pF	C _L = 1	5 pF	UNIT
FARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _{PLH}	A or B	B or A	0	0.8	0	0.6	0	0.3	20
t _{PHL}	AUID	BUIA	0	1.2	0	1	0	0.5	ns

Switching Characteristics

over recommended operating free-air temperature range, $V_{GATE} = 2.5 \text{ V}$, $V_{IH} = 2.5 \text{ V}$, $V_{IL} = 0$, and $V_{M} = 0.75 \text{ V}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	C _L = 5	0 pF	C _L = 30 pF		C _L = 15 pF		UNIT
FARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _{PLH}	A or B	B or A	0	1	0	0.7	0	0.4	20
t _{PHL}	AUD	BUIA	0	1.3	0	1	0	0.6	ns

AC Performance (Translating Up) Switching Characteristics over recommended operating free-air temperature range, $V_{GATE} = 3.3$ V, $V_{IH} = 2.3$ V, $V_{IL} = 0$, $V_T = 3.3$ V, $V_M = 1.15$ V, and $R_1 = 300 \Omega$ (unless otherwise noted) (see Figure 1) $R_1 = 300 \Omega$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM TO		TO C _L = 50 pF C _L = 30 pF		C _L = 15 pF	UNIT
FARAINETER	(INPUT)	(OUTPUT)	MIN MAX	MIN MAX	MIN MAX	UNIT
t _{PLH}	A or B	B or A	0 0.9	0 0.6	0 0.4	20
t _{PHL}	AULP	BUIA	0 1.4	0 1.1	0 0.7	ns

Switching Characteristics

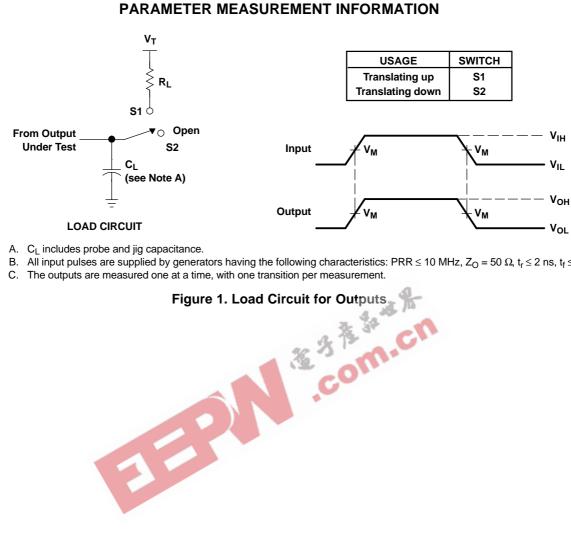
over recommended operating free-air temperature range, $V_{GATE} = 2.5$ V, $V_{IH} = 1.5$ V, $V_{IL} = 0$, $V_T = 2.5$ V, $V_M = 0.75$ V, and $R_1 = 300 \Omega$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	C _L = 5	0 pF	C _L = 3	0 pF	C _L = 1	5 pF	UNIT
PARAMIETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _{PLH}	A or B	B or A	0	1	0	0.6	0	0.4	20
t _{PHL}	AUD	DOLA	0	1.3	0	1.3	0	0.8	ns

SN74TVC3306 **DUAL VOLTAGE CLAMP**

TEXAS STRUMENTS www.ti.com

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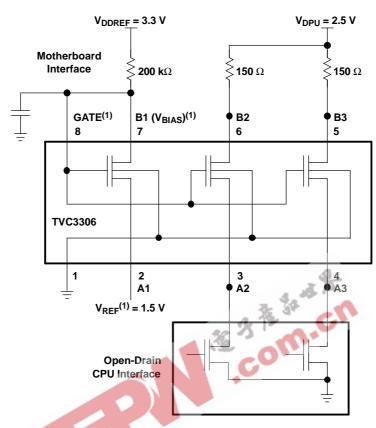


NOTES: A. CL includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z₀ = 50 Ω , t_f \leq 2 ns, t_f \leq 2 ns.
- C. The outputs are measured one at a time, with one transition per measurement.



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APPLICATION INFORMATION

(1) V_{REF} and V_{BIAS} can be applied to any one of the pass transistors. GATE must be connected externally to V_{BIAS}.

Figure 2. Typical Application Circuit

For the clamping configuration, the common GATE input must be connected to one side (An or Bn) of any one of the pass transistors, making that the V_{BIAS} connection of the reference transistor and the opposite side (Bn or An) the V_{REF} connection. When V_{BIAS} is connected through a 200-k Ω resistor to a 3-V to 5.5-V V_{CC} supply and V_{REF} is set to 0 V to V_{CC} – 0.6 V, the output of each switch has a maximum clamp voltage equal to V_{REF}. A filter capacitor on V_{BIAS} is recommended.

Application Operating Conditions

see Figure 2

		MIN	TYP ⁽¹⁾	MAX	UNIT
V _{BIAS}	BIAS voltage	V _{REF} + 0.6	2.1	5	V
V _{GATE}	GATE voltage	V _{REF} + 0.6	2.1	5	V
V_{REF}	Reference voltage	0	1.5	4.4	V
V _{DPU}	Drain pullup voltage	2.36	2.5	2.64	V
I _{PASS}	Pass-transistor current		14		mA
I _{REF}	Reference-transistor current		5		μA
T _A	Operating free-air temperature	-40		85	°C

(1) All typical values are at $T_A = 25^{\circ}C$.

20-Mar-2006

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN74TVC3306DCTR	ACTIVE	SM8	DCT	8	3000	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74TVC3306DCTRE4	ACTIVE	SM8	DCT	8	3000	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
SN74TVC3306DCUR	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74TVC3306DCURE4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD**: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

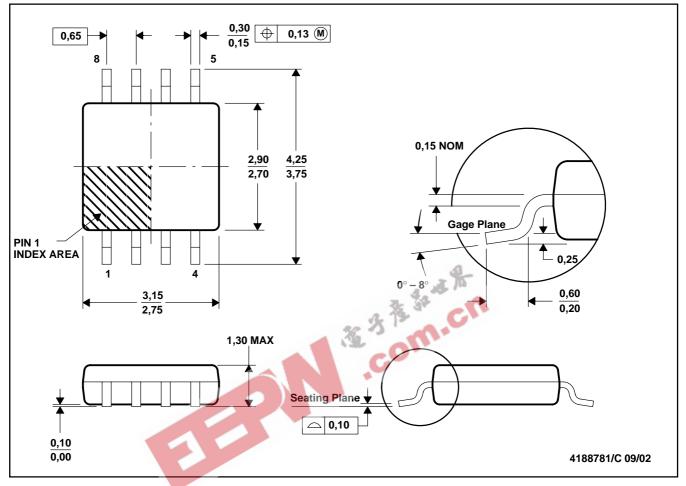
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MECHANICAL DATA

MPDS049B - MAY 1999 - REVISED OCTOBER 2002

PLASTIC SMALL-OUTLINE PACKAGE

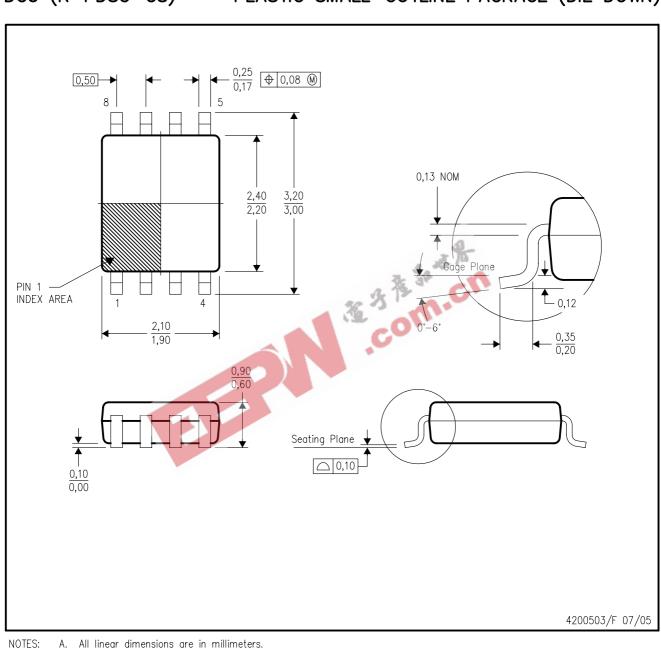


NOTES: A. All linear dimensions are in millimeters.

DCT (R-PDSO-G8)

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion
- D. Falls within JEDEC MO-187 variation DA.





DCU (R-PDSO-G8) PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)

- Β. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-187 variation CA.



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